RŏHS

**UMSB** 



### **GLASS PASSIVATED SURFACE MOUNT BRIDGE RECTIFIERS**

## **Features**

- ♦ Glass Passivated Chip Junction
- ◆ Reverse Voltage 60 V
- ◆ Forward Current 5.0 A
- ♦ High Surge Current Capability
- ◆ Designed for Surface Mount Application

# **Mechanical Data**

Case : JEDEC UMSB molded plastic body

Terminals: Solderable per MIL-STD-750, Method 2026 Á

Polarity: Polarity symbol marking on body

Mounting Position: Any

Weight: 0.00824 ounce, 0.2337 grams

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Dimensions in inches and (millimeters)

# **Maximum Ratings And Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter	Symbols	MDD MSB56	Units
Marking Code	Syllibols		
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	60	V
Maximum RMS voltage	V <sub>RMS</sub>	42	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	60	V
Maximum Average Forward Rectified Current	Io	5	А
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>	80	А
Maximum Forward Voltage	VF	0.45(TYP) 0.59	V
Maximum DC Reverse Current at Rated DC Blocking Voltage $@T_a=25^{\circ}C$	I <sub>R</sub>	0.3	mA
Typical Junction Capacitance (Note 1)	C <sub>j</sub>	300	pF
Operating Temperature Range	Tj	-55 ~ +150	°C
Storage Temperature Range	T <sub>stg</sub>	-55 ~ +150	°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

2. Mounted on glass epoxy PC board with 4×1.5"×1.5" (  $3.81\times3.81$  cm ) copper pad.



# **Typical Characterisitics**

Fig.1 Average Rectified Output Current Derating Curve

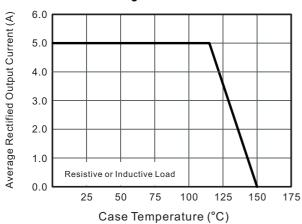


Fig.2 Typical Reverse Characteristics

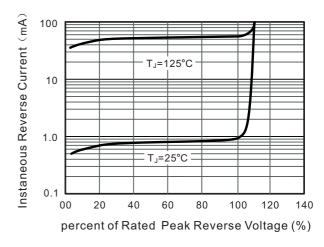


Fig.3 Typical Instaneous Forward Characteristics

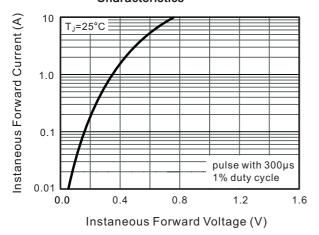


Fig.4 Typical Junction Capacitance

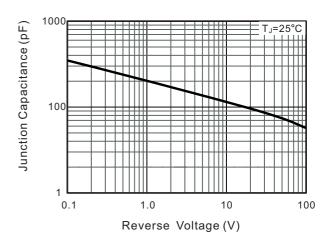
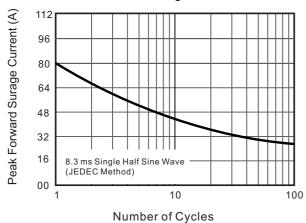


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current

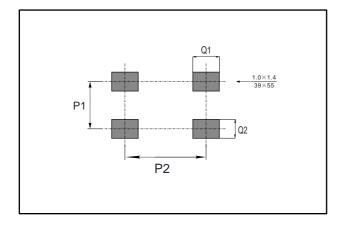


The curve above is for reference only.

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### **Suggested Pad Layout**



Dim	Min
P1	5.1
P2	7.1
Q1	1.8
Q2	1.3

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